

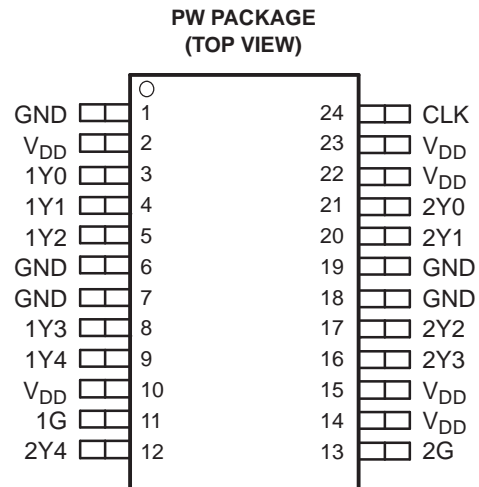
2.5-V TO 3.3-V HIGH-PERFORMANCE CLOCK BUFFER

FEATURES

- High-Performance 1:10 Clock Driver
- Operates up to 200 MHz at V_{DD} 3.3 V
- Pin-to-Pin Skew < 100 ps at V_{DD} 3.3 V
- V_{DD} Range: 2.3 V to 3.6 V
- Operating Temperature Range -40°C to 85°C
- Output Enable Glitch Suppression
- Distributes One Clock Input to Two Banks of Five Outputs
- 25- Ω On-Chip Series Damping Resistors
- Packaged in 24-Pin TSSOP

APPLICATIONS

- General-Purpose Applications



DESCRIPTION

The CDCVF2310 is a high-performance, low-skew clock buffer that operates up to 200 MHz. Two banks of five outputs each provide low-skew copies of CLK. After power up, the default state of the outputs is low regardless of the state of the control pins. For normal operation, the outputs of bank 1Y[0:4] or 2Y[0:4] can be placed in a low state when the control pins (1G or 2G, respectively) are held low and a negative clock edge is detected on the CLK input. The outputs of bank 1Y[0:4] or 2Y[0:4] can be switched into the buffer mode when the control pins (1G and 2G) are held high and a negative clock edge is detected on the CLK input. The device operates in a 2.5-V and 3.3-V environment. The built-in output enable glitch suppression ensures a synchronized output enable sequence to distribute full period clock signals.

The CDCVF2310 is characterized for operation from -40°C to 85°C .

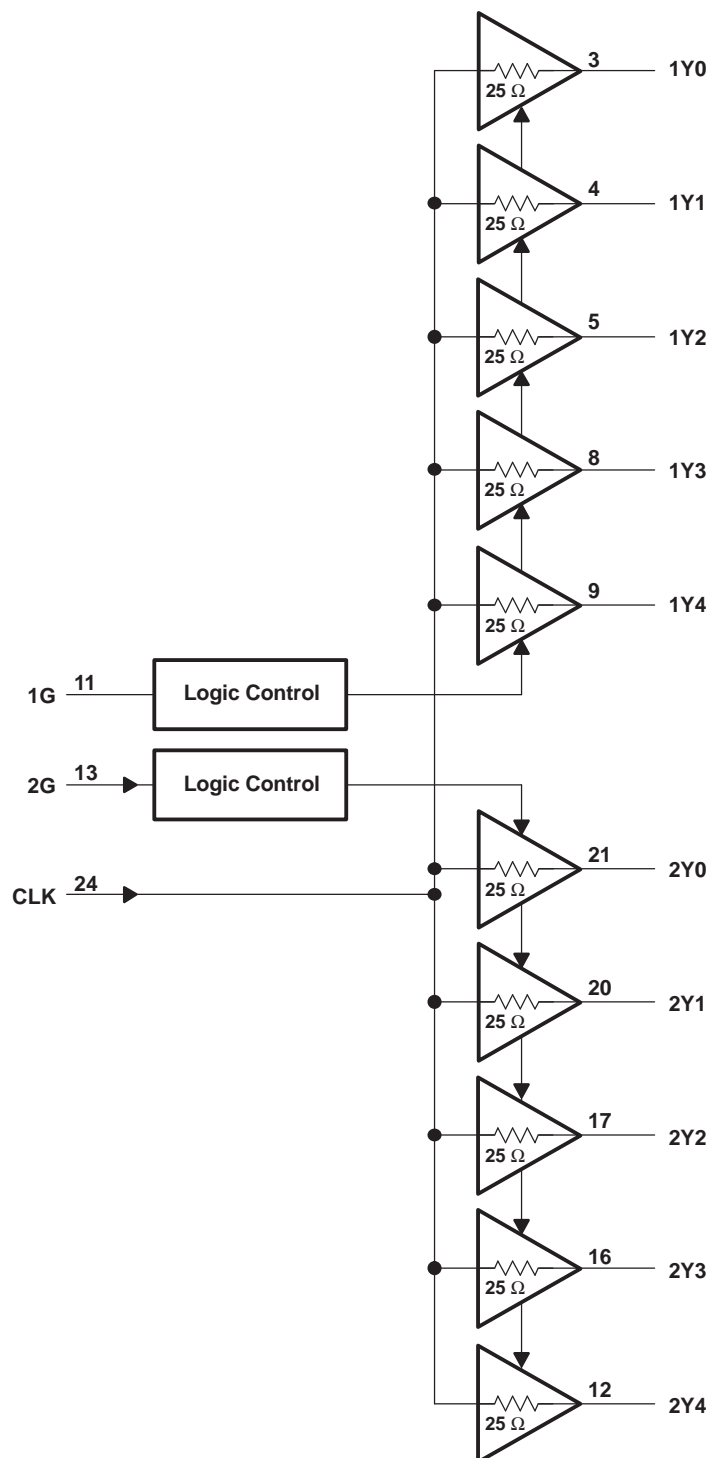


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



FUNCTION TABLE

INPUT			OUTPUT	
1G	2G	CLK	1Y[0:4]	2Y[0:4]
L	L	↓	L	L
H	L	↓	CLK ⁽¹⁾	L
L	H	↓	L	CLK ⁽¹⁾
H	H	↓	CLK ⁽¹⁾	CLK ⁽¹⁾

- (1) After detecting one negative edge on the CLK input, the output follows the input CLK if the control pin is held high.

Terminal Functions

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
1G	11	I	Output enable control for 1Y[0:4] outputs. This output enable is active-high, meaning the 1Y[0:4] clock outputs follow the input clock (CLK) if this pin is logic high.
2G	13	I	Output enable control for 2Y[0:4] outputs. This output enable is active-high, meaning the 2Y[0:4] clock outputs follow the input clock (CLK) if this pin is logic high.
1Y[0:4]	3, 4, 5, 8, 9	O	Buffered output clocks
2Y[0:4]	21, 20, 17, 16, 12	O	Buffered output clocks
CLK	24	I	Input reference frequency
GND	1, 6, 7, 18, 19		Ground
V _{DD}	2, 10, 14, 15, 22, 23		DC power supply, 2.3 V – 3.6 V

DETAILED DESCRIPTION

Output Enable Glitch Suppression Circuit

The purpose of the glitch suppression circuitry is to ensure the output enable sequence is synchronized with the clock input such that the output buffer is enabled or disabled on the next full period of the input clock (negative edge triggered by the input clock) (see [Figure 1](#)).

The G input must fulfill the timing requirements (t_{su} , t_h) according to the *Switching Characteristics* table for predictable operation.

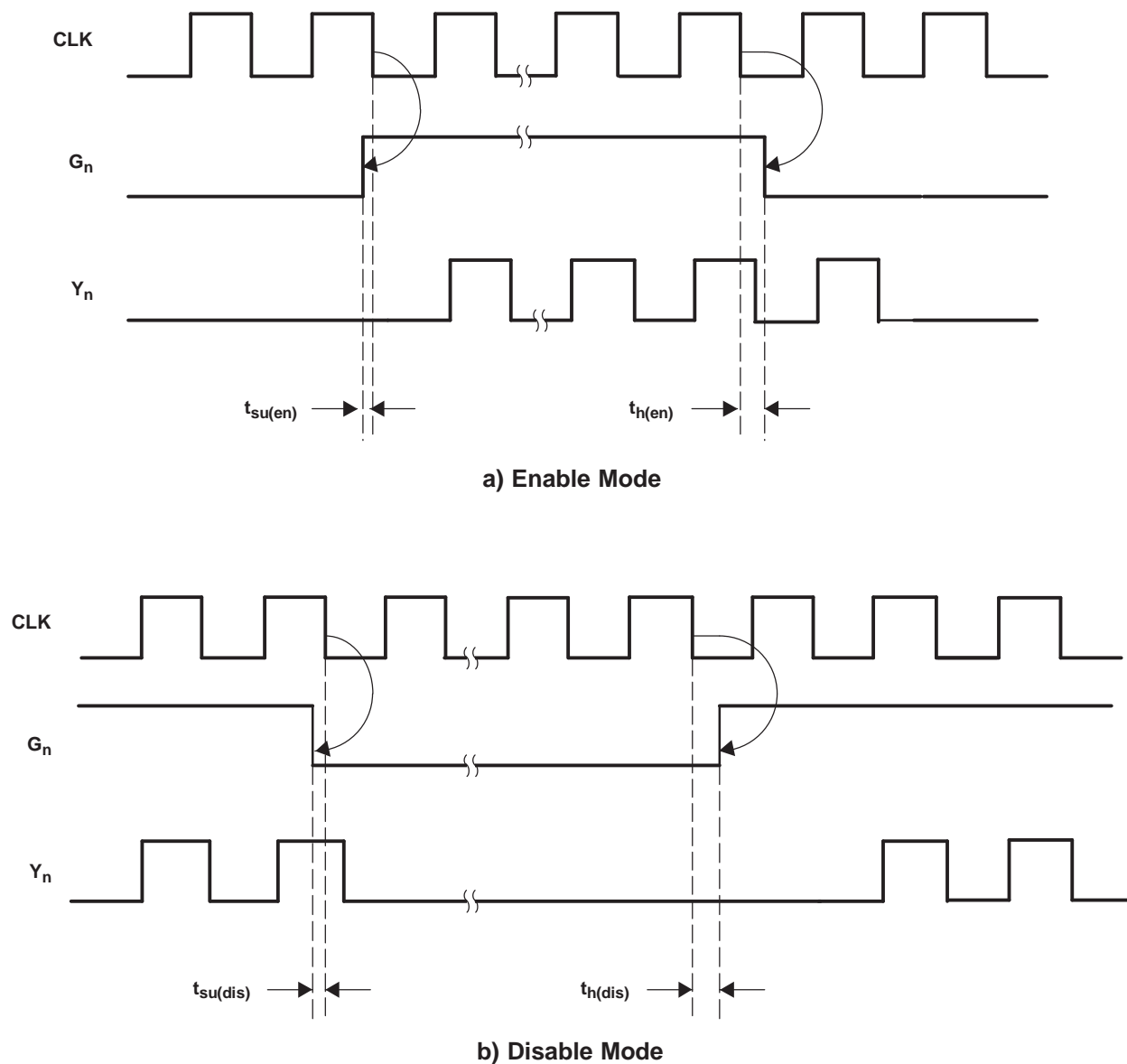


Figure 1. Enable and Disable Mode Relative to CLK↓

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

Supply voltage range, V_{DD}	–0.5 V to 4.6 V
Input voltage range, V_I ⁽²⁾⁽³⁾	–0.5 V to $V_{DD} + 0.5$ V
Output voltage range, V_O ⁽²⁾⁽³⁾	–0.5 V to $V_{DD} + 0.5$ V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{DD}$)	±50 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{DD}$)	±50 mA
Continuous total output current, I_O ($V_O = 0$ to V_{DD})	±50 mA
Package thermal impedance, θ_{JA} ⁽⁴⁾ : PW package	120°C/W
Storage temperature range T_{stg}	–65°C to 150°C

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (3) This value is limited to 4.6 V maximum.
- (4) The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS ⁽¹⁾

		MIN	NOM	MAX	UNIT
Supply voltage, V_{DD}		2.3	2.5		V
			3.3	3.6	
Low-level input voltage, V_{IL}	$V_{DD} = 3$ V to 3.6 V			0.8	V
	$V_{DD} = 2.3$ V to 2.7 V			0.7	
High-level input voltage, V_{IH}	$V_{DD} = 3$ V to 3.6 V	2			V
	$V_{DD} = 2.3$ V to 2.7 V	1.7			
Input voltage, V_I		0		V_{DD}	V
High-level output current, I_{OH}	$V_{DD} = 3$ V to 3.6 V			12	mA
	$V_{DD} = 2.3$ V to 2.7 V			6	
Low-level output current, I_{OL}	$V_{DD} = 3$ V to 3.6 V			12	mA
	$V_{DD} = 2.3$ V to 2.7 V			6	
Operating free-air temperature, T_A		–40		85	°C

- (1) Unused inputs must be held high or low to prevent them from floating.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}	Input voltage	$V_{DD} = 3$ V,	$I_I = -18$ mA			–1.2	V
I_I	Input current	$V_I = 0$ V or V_{DD}				±5	μA
I_{DD} ⁽²⁾	Static device current	CLK = 0 V or V_{DD} ,	$I_O = 0$ mA			80	μA
C_I	Input capacitance	$V_{DD} = 2.3$ V to 3.6 V,	$V_I = 0$ V or V_{DD}		2.5		pF
C_O	Output capacitance	$V_{DD} = 2.3$ V to 3.6 V,	$V_I = 0$ V or V_{DD}		2.8		pF

- (1) All typical values are at respective nominal V_{DD} .
- (2) For I_{CC} over frequency, see [Figure 6](#).

$V_{DD} = 3.3$ V ±0.3 V

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V_{OH}	High-level output voltage	$V_{DD} = \text{min to max,}$	$I_{OH} = -100$ μA	$V_{DD} - 0.2$			V
		$V_{DD} = 3$ V	$I_{OH} = -12$ mA	2.1			
			$I_{OH} = -6$ mA	2.4			

- (1) All typical values are at respective nominal V_{DD} .

V_{DD} = 3.3 V ±0.3 V (continued)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OL}	Low-level output voltage	V _{DD} = min to max, I _{OL} = –100 µA				0.2	V
		V _{DD} = 3 V	I _{OL} = 12 mA			0.8	
			I _{OL} = 6 mA			0.55	
I _{OH}	High-level output current	V _{DD} = 3 V,	V _O = 1 V	–28			mA
		V _{DD} = 3.3 V,	V _O = 1.65 V	–36			
		V _{DD} = 3.6 V,	V _O = 3.135 V	–14			
I _{OL}	Low-level output current	V _{DD} = 3 V,	V _O = 1.95 V	28			mA
		V _{DD} = 3.3 V,	V _O = 1.65 V	36			
		V _{DD} = 3.6 V,	V _O = 0.4 V	14			

V_{DD} = 2.5 V ±0.2 V

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	High-level output voltage	V _{DD} = min to max, I _{OH} = –100 µA		V _{DD} – 0.2			V
		V _{DD} = 2.3 V, I _{OH} = –6 mA		1.8			
V _{OL}	Low-level output voltage	V _{DD} = min to max, I _{OL} = 100 µA				0.2	V
		V _{DD} = 2.3 V, I _{OL} = 6 mA				0.55	
I _{OH}	High-level output current	V _{DD} = 2.3 V,	V _O = 1 V	–17			mA
		V _{DD} = 2.5 V,	V _O = 1.25 V	–25			
		V _{DD} = 2.7 V,	V _O = 2.375 V	–10			
I _{OL}	Low-level output current	V _{DD} = 2.3 V,	V _O = 1.2 V	17			mA
		V _{DD} = 2.5 V,	V _O = 1.25 V	25			
		V _{DD} = 2.7 V,	V _O = 0.3 V	10			

(1) All typical values are at respective nominal V_{DD}.**TIMING REQUIREMENTS**

over recommended ranges of supply voltage and operating free-air temperature

			MIN	NOM	MAX	UNIT
f _{clk}	Clock frequency	V _{DD} = 3 V to 3.6 V	0		200	MHz
		V _{DD} = 2.3 V to 2.7 V	0		170	

JITTER CHARACTERISTICSCharacterized using CDCVF2310 Performance EVM when V_{DD}=3.3 V. Outputs not under test are terminated to 50 Ω.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _{jitter}	Additive phase jitter from input to output 1Y0	12 kHz to 5 MHz, f _{out} = 30.72 MHz			52		fs rms
		12 kHz to 20 MHz, f _{out} = 125 MHz			45		

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

$V_{DD} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (see Figure 2)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	CLK to Y_n	$f = 0 \text{ MHz to } 200 \text{ MHz}$ For circuit load, see Figure 2.	1.3		2.8	ns
t_{PHL}						
$t_{sk(o)}$	Output skew (Y_m to Y_n) ⁽¹⁾ (see Figure 4)				100	ps
$t_{sk(p)}$	Pulse skew (see Figure 5)				250	ps
$t_{sk(pp)}$	Part-to-part skew				500	ps
t_r	Rise time (see Figure 3)	$V_O = 0.4 \text{ V to } 2 \text{ V}$	0.7		2	V/ns
t_f	Fall time (see Figure 3)	$V_O = 2 \text{ V to } 0.4 \text{ V}$	0.7		2	V/ns
$t_{su(en)}$	Enable setup time, G_{high} before CLK ↓		0.1			ns
$t_{su(dis)}$	Disable setup time, G_{low} before CLK ↓		0.1			ns
$t_{h(en)}$	Enable hold time, G_{high} after CLK ↓		0.4			ns
$t_{h(dis)}$	Disable hold time, G_{low} after CLK ↓		0.4			ns

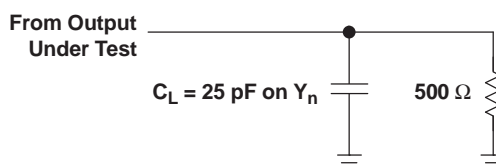
(1) The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.

$V_{DD} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (see Figure 2)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	CLK to Y_n	$f = 0 \text{ MHz to } 170 \text{ MHz}$ For circuit load, see Figure 2.	1.5		3.5	ns
t_{PHL}						
$t_{sk(o)}$	Output skew (Y_m to Y_n) ⁽¹⁾ (see Figure 4)				170	ps
$t_{sk(p)}$	Pulse skew (see Figure 5)				400	ps
$t_{sk(pp)}$	Part-to-part skew				600	ps
t_r	Rise time (see Figure 3)	$V_O = 0.4 \text{ V to } 1.7 \text{ V}$	0.5		1.4	V/ns
t_f	Fall time (see Figure 3)	$V_O = 1.7 \text{ V to } 0.4 \text{ V}$	0.5		1.4	V/ns
$t_{su(en)}$	Enable setup time, G_{high} before CLK ↓		0.1			ns
$t_{su(dis)}$	Disable setup time, G_{low} before CLK ↓		0.1			ns
$t_{h(en)}$	Enable hold time, G_{high} after CLK ↓		0.4			ns
$t_{h(dis)}$	Disable hold time, G_{low} after CLK ↓		0.4			ns

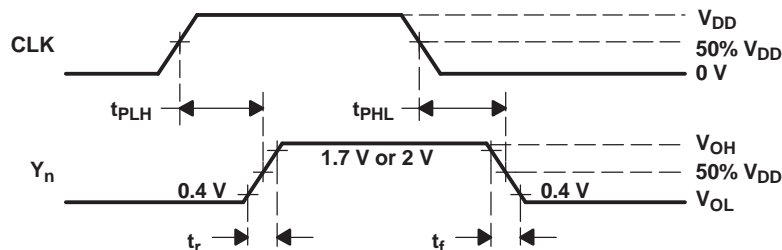
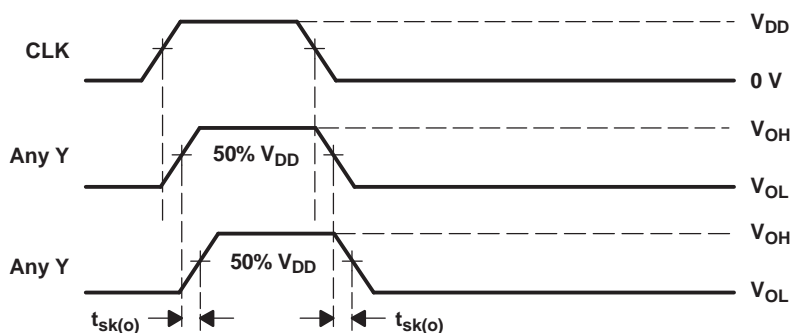
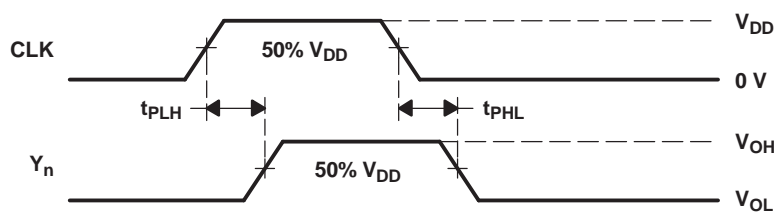
(1) The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.

PARAMETER MEASUREMENT INFORMATION



- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 200 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 1.2 \text{ ns}$, $t_f < 1.2 \text{ ns}$.

Figure 2. Test Load Circuit

PARAMETER MEASUREMENT INFORMATION (continued)**Figure 3. Voltage Waveforms Propagation Delay Times****Figure 4. Output Skew**NOTE: $t_{sk(p)} = |t_{PLH} - t_{PHL}|$ **Figure 5. Pulse Skew**

PARAMETER MEASUREMENT INFORMATION (continued)

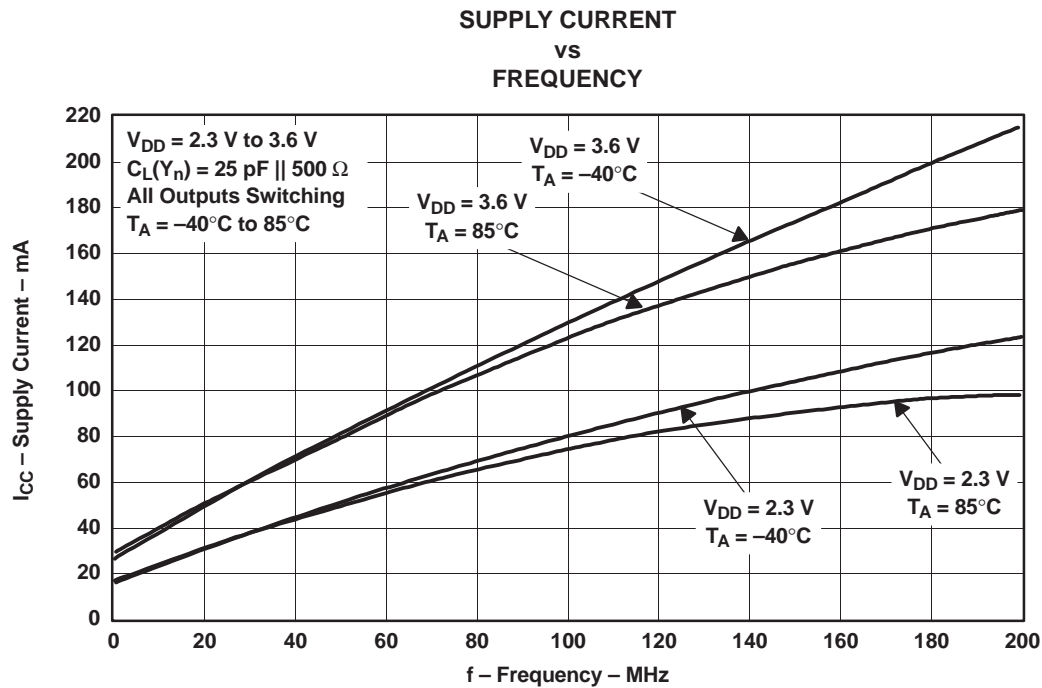


Figure 6.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
CDCVF2310PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV2310	Samples
CDCVF2310PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV2310	Samples
CDCVF2310PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV2310	Samples
CDCVF2310PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV2310	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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OTHER QUALIFIED VERSIONS OF CDCVF2310 :

- Enhanced Product: [CDCVF2310-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCVF2310PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

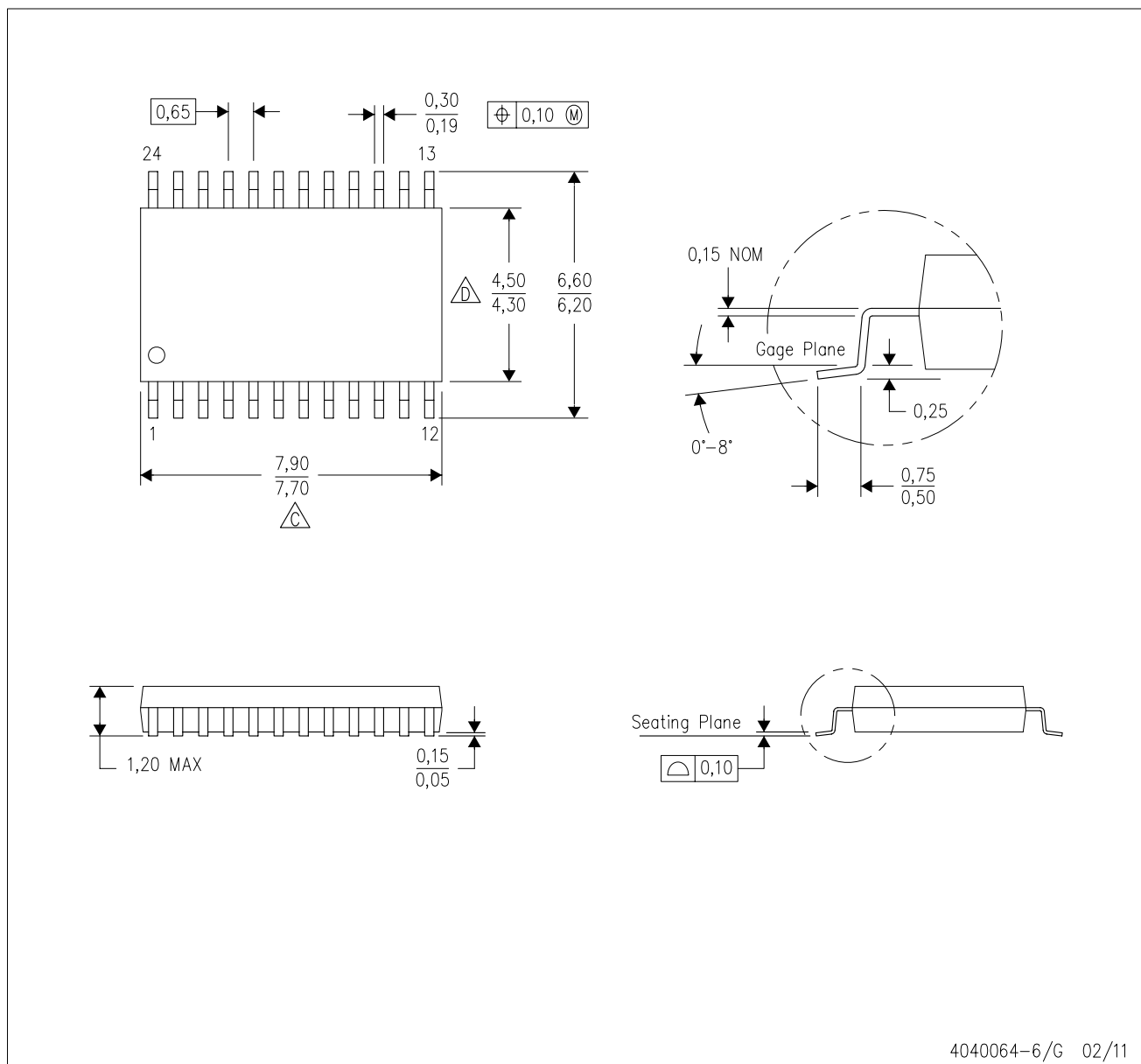


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCVF2310PWR	TSSOP	PW	24	2000	367.0	367.0	38.0

PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE

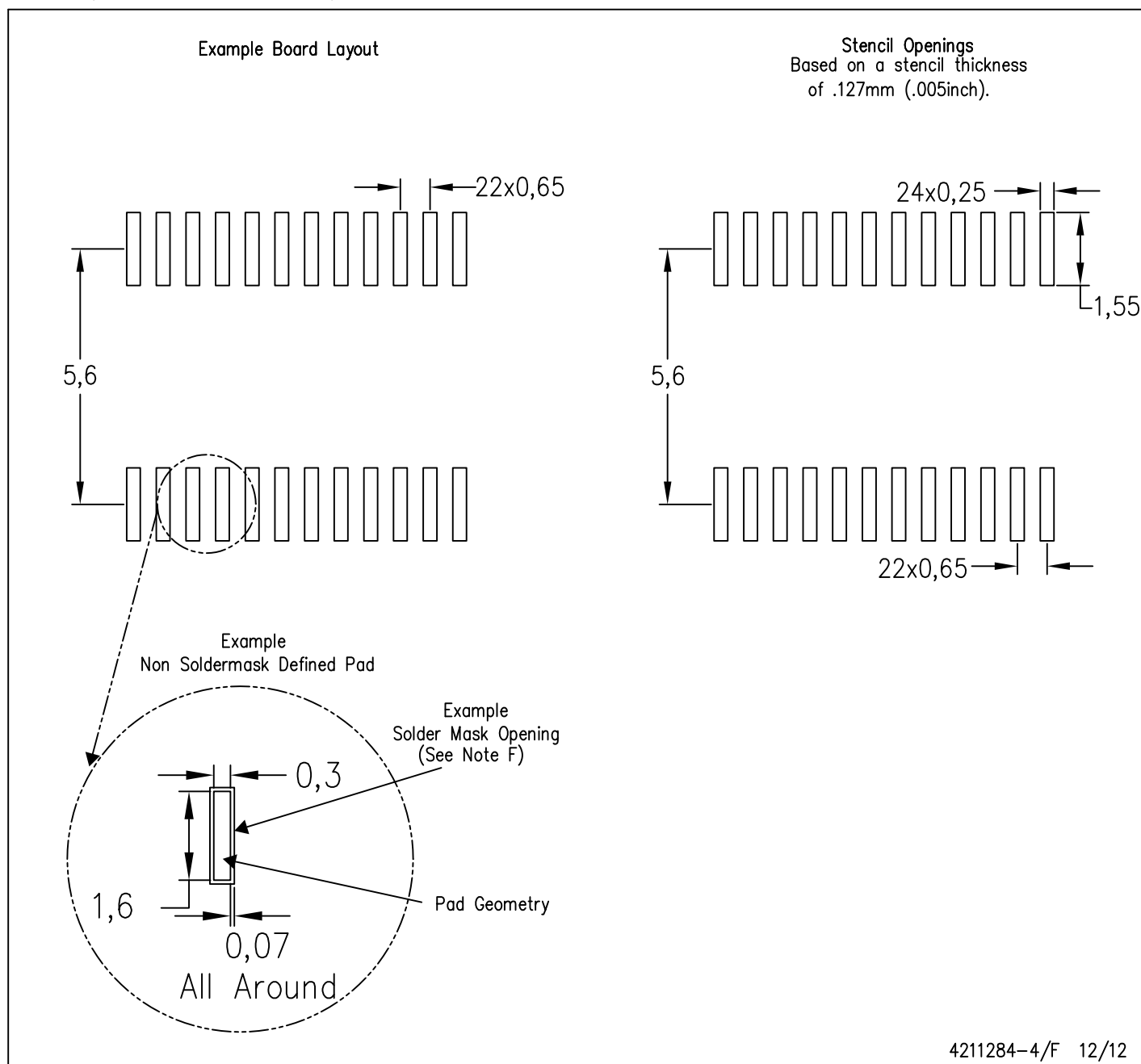


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- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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